High voltage discharge, High speed switching, Low Noise (-60V, -3A)

2SA2073

Features

- 1) High speed switching. (tf:Typ.:20ns at Ic=-3A)
- 2) Low saturation voltage, typically.

(Typ.:-200mV at Ic=-2.0A, IB=-200mA)

- 3) Strong discharge power for inductive load and capacitance load.
- 4) Low Noise.
- 5) Complements the 2SC5826.

Applications

High speed switching, Low noise

Structure

PNP silicon epitaxial planar transistor

Packaging specifications

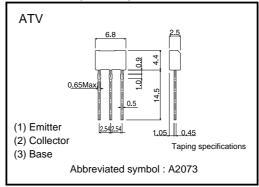
Туре	Package	Taping
	Code	TV2
	Basic ordering unit (pieces)	2500
2SA2073		0

● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		Vсво	-60	V
Collector-emitter voltage		Vceo	-60	V
Emitter-base voltage		VEBO	-6	V
Collector current	DC	Ic	-3	А
	Pulsed	Icp	-6	Α *
Power dissipation		Pc	1.0	W
Junction temperature		tj	150	°C
Range of storage temperature		tstg	-55 to 150	°C

^{*}Pw=10ms

●Dimensions (Unit: mm)



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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition	
Collector-emitter breakdown voltage	BVceo	-60	-	-	V	Ic=-1mA	
Collector-base breakdown voltage	ВУсво	-60	_	_	V	Ic=-100μA	
Emitter-base breakdown voltage	ВVево	-6	_	-	V	IE=-100μA	
Collector cut-off current	Ісво	_	_	-1.0	μΑ	VcB=-40V	
Emitter cut-off current	ІЕВО	_	-	-1.0	μΑ	V _{EB} =-4V	
Collector-emitter saturation voltage	VCE (sat)	_	-200	-500	mV	Ic=-2.0A *1	
						I _B =-200mA	
DC current gain	hfE	120	_	270	_	Vce=-2V	
						Ic=-100mA	
					MHz	Vc==-10V *1	
Transistor frequency	f⊤	_	200	_		IE=100mA	
						f=10MHz	
	Cob	_	40	_	pF	Vcb=-10V	
Collector output capacitance						IE=0mA	
						f=1MHz	
Turn-on time	ton		20		ns	Ic=-3A *2	
Storage time	tstg	_	130	_	ns	Iв1=-300mA Iв2=300mA	
Fall time	tf	_	20	_	ns	Vcc≃ –25 V	

●hFE RANK

Q	
120–270	

^{*1} Single pulse *2 See switching characteristics measurement circuits

•Electrical characteristics curves

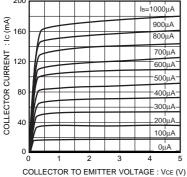


Fig.1 Typical output characteristics

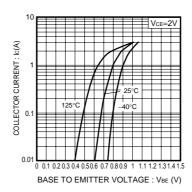


Fig.2 Grounded emitter propagation characteristics

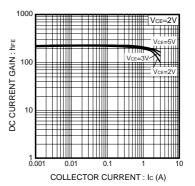


Fig.3 DC current gain vs.collector current (I)

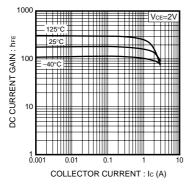


Fig.4 DC current gain vs.collector current (II)

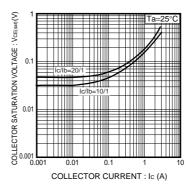


Fig.5 Collector-emitter saturation voltage vs.collector current (I)

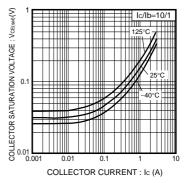


Fig.6 Collector-emitter saturation voltage vs.collector current (II)

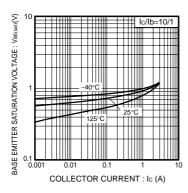


Fig.7 Base-emitter saturation voltage vs. collector current

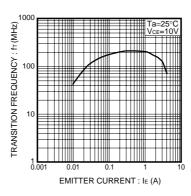


Fig.8 Transition frequency

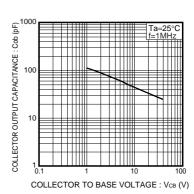
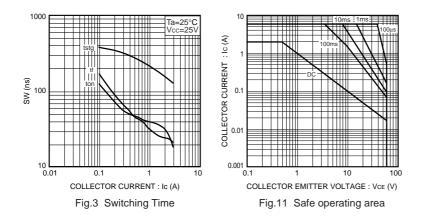
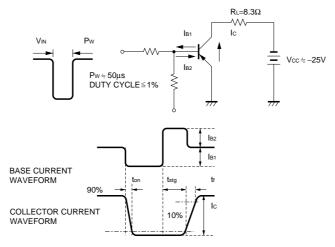


Fig.9 Collector output capacitance

Rev.A



•Switching characteristics measurement circuits



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